TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π -MOSVII)

TK7P50D

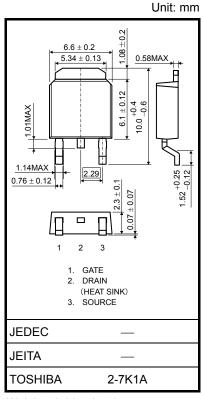
Switching Regulator Applications

• Low drain-source ON-resistance: $RDS(ON) = 1.0 \Omega$ (typ.)

- High forward transfer admittance: $|Y_{fs}| = 2.5 \text{ S}$ (typ.)
- Low leakage current: $I_{DSS} = 10 \ \mu A (max) (V_{DS} = 500 \ V)$
- Enhancement-mode: $V_{th} = 2.4$ to 4.4 V ($V_{DS} = 10$ V, $I_D = 1$ mA)

Characteristics		Symbol	Rating	Unit	
Drain-source voltage		V _{DSS}	500	V	
Gate-source voltage		V _{GSS}	±30	V	
Drain current	DC (Note 1)	۱ _D	7		
	Pulse (t = 1 ms) (Note 1)	I _{DP}	28	A	
Drain power dissipati	on (Tc = 25°C)	PD	100	W	
Single pulse avalanche energy (Note 2)		E _{AS}	105	mJ	
Avalanche current		I _{AR}	7	А	
Repetitive avalanche energy (Note 3)		E _{AR}	10	mJ	
Channel temperature		T _{ch}	150	°C	
Storage temperature range		T _{stg}	–55 to 150	°C	

Absolute Maximum Ratings (Ta = 25°C)



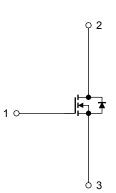
Weight : 0.36 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	R _{th (ch-c)}	1.25	°C/W
Thermal resistance, channel to ambient	R _{th (ch-a)}	125	°C/W

Internal Connection



Note 1: Please use devices on conditions that the channel temperature is below 150°C.

Note 2: V_{DD} = 90 V, T_{ch} = 25°C (initial), L = 3.64 mH, R_G = 25 Ω , I_{AR} = 7 A

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic sensitive device. Please handle with caution.

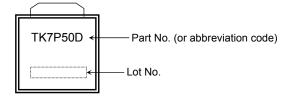
Electrical Characteristics (Ta = 25°C)

Char	acteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I _{GSS}	$V_{GS}=\pm 30~V,~V_{DS}=0~V$	_	—	±1	μA
Drain cut-off current		I _{DSS}	$V_{DS} = 500 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$	_		10	μA
Drain-source breakdown voltage		V (BR) DSS	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	500			V
Gate threshold v	oltage	V _{th}	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 1 \text{ mA}$	2.4		4.4	V
Drain-source ON	l-resistance	R _{DS (ON)}	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 3.5 \text{ A}$		1.0	1.22	Ω
Forward transfer	admittance	Y _{fs}	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 3.5 \text{ A}$	0.7	2.5		S
Input capacitance		C _{iss}		_	600	_	
Reverse transfer capacitance		C _{rss}	V _{DS} = 25 V, V _{GS} = 0 V, f = 1 MHz	_	4	_	pF
Output capacitance		C _{oss}			70		
Switching time	Rise time	tr	V_{GS}		18		
	Turn-on time	t _{on}	$\begin{array}{c} & & & \\ & & & & \\ & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & & & \\ & & &$		40		ns
	Fall time	t _f			8		
	Turn-off time	t _{off}			55		
Total gate charge		Qg		_	12		
Gate-source charge		Q _{gs}	$V_{DD} \approx 400 \text{ V}, \text{ V}_{GS} = 10 \text{ V}, \text{ I}_{D} = 7 \text{ A}$	_	7		nC
Gate-drain charge		Q _{gd}	1	—	5		

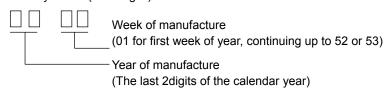
Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I _{DR}	_	_	_	7	А
Pulse drain reverse current (Note 1)	I _{DRP}	_	_		28	А
Forward voltage (diode)	V _{DSF}	$I_{DR} = 7 \text{ A}, V_{GS} = 0 \text{ V}$	_	_	-1.7	V
Reverse recovery time	t _{rr}	$I_{DR} = 7 \text{ A}, V_{GS} = 0 \text{ V},$	_	1200	_	ns
Reverse recovery charge	Q _{rr}	dl _{DR} /dt = 100 A/μs	_	7	_	μC

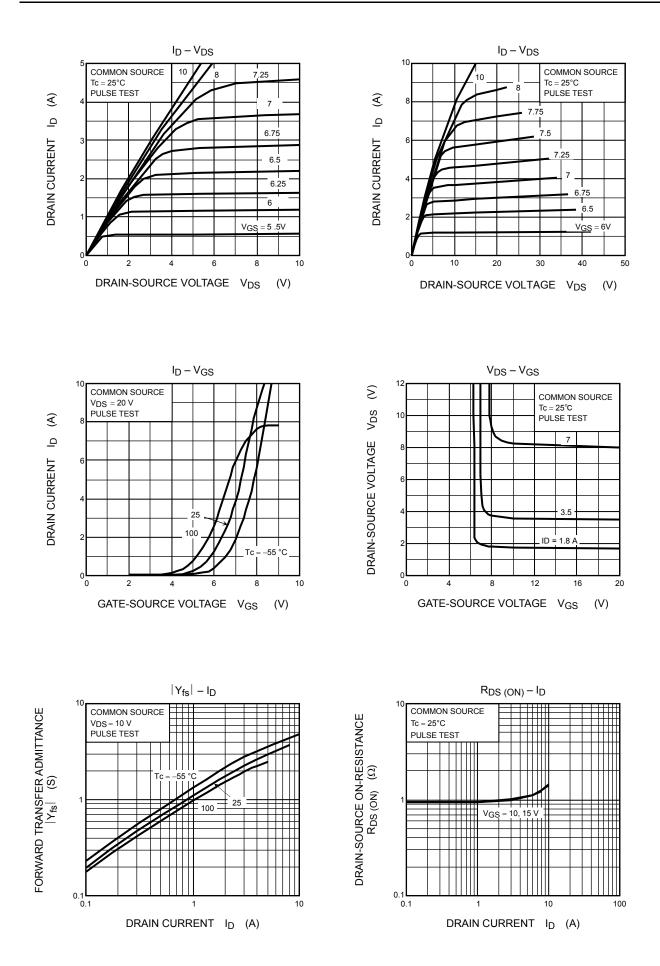
Marking (Note 4)



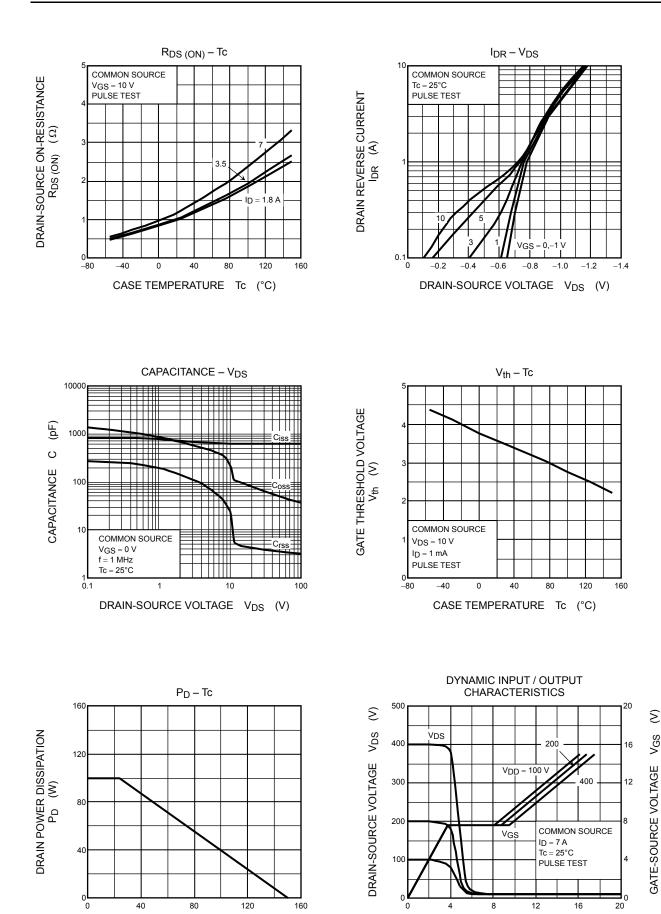
Note 4: * Weekly code: (Four digits)



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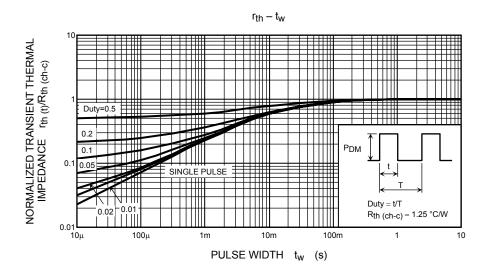


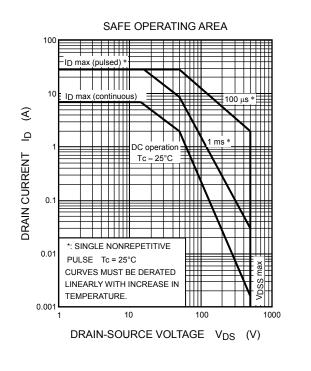
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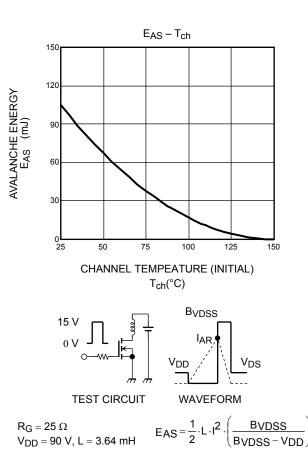


TOTAL GATE CHARGE Q_g (nC)

CASE TEMPERATURE Tc (°C)







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